

SN54HC30, SN74HC30 8-INPUT POSITIVE-NAND GATES

D2684, DECEMBER 1982—REVISED SEPTEMBER 1987

- Package Options Include Plastic "Small Outline" Packages, Ceramic Chip Carriers, and Standard Plastic and Ceramic 300-mil DIPs
- Dependable Texas Instruments Quality and Reliability

description

These devices contain a single 8-input NAND gate and perform the following Boolean functions in positive logic:

$$Y = \overline{A \cdot B \cdot C \cdot D \cdot E \cdot F \cdot G \cdot H}$$

or

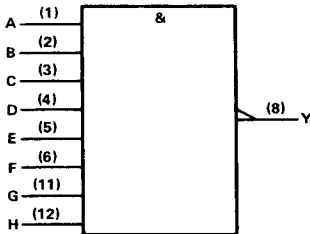
$$Y = \overline{A} + \overline{B} + \overline{C} + \overline{D} + \overline{E} + \overline{F} + \overline{G} + \overline{H}$$

The SN54HC30 is characterized for operation over the full military temperature range of -55°C to 125°C . The SN74HC30 is characterized for operation from -40°C to 85°C .

FUNCTION TABLE

INPUTS A THRU H	OUTPUT Y
All inputs H	L
One or more inputs L	H

logic symbol†

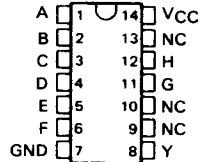


†This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

Pin numbers shown are for D, J, and N packages.

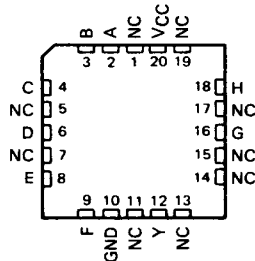
SN54HC30 . . . J PACKAGE
SN74HC30 . . . D OR N PACKAGE

(TOP VIEW)



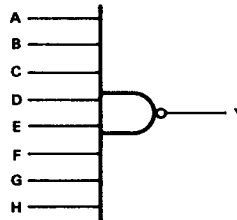
SN54HC30 . . . FK PACKAGE

(TOP VIEW)



NC—No internal connection

logic diagram (positive logic)



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HC MOS Devices

PRODUCTION DATA documents contain information current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

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INSTRUMENTS

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absolute maximum ratings over operating free-air temperature range†

Supply voltage, V_{CC}	–0.5 V to 7 V
Input clamp current, I_{IK} ($V_I < 0$ or $V_I > V_{CC}$)	±20 mA
Output clamp current, I_{OK} ($V_O < 0$ or $V_O > V_{CC}$)	±20 mA
Continuous output current, I_O ($V_O = 0$ to V_{CC})	±25 mA
Continuous current through V_{CC} or GND pins	±50 mA
Lead temperature 1,6 mm (1/16 in) from case for 60 s: FK or J package	300°C
Lead temperature 1,6 mm (1/16 in) from case for 10 s: D or N package	260°C
Storage temperature range	–65°C to 150°C

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions

		SN54HC30			SN74HC30			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	
V_{CC} Supply voltage		2	5	6	2	5	6	V
V_{IH} High-level input voltage	$V_{CC} = 2$ V	1.5			1.5			V
	$V_{CC} = 4.5$ V	3.15			3.15			
	$V_{CC} = 6$ V	4.2			4.2			
V_{IL} Low-level input voltage	$V_{CC} = 2$ V	0	0.3		0	0.3		V
	$V_{CC} = 4.5$ V	0	0.9		0	0.9		
	$V_{CC} = 6$ V	0	1.2		0	1.2		
V_I Input voltage		0	V_{CC}		0	V_{CC}		V
V_O Output voltage		0	V_{CC}		0	V_{CC}		V
t_t Input transition (rise and fall) times	$V_{CC} = 2$ V	0	1000		0	1000		ns
	$V_{CC} = 4.5$ V	0	500		0	500		
	$V_{CC} = 6$ V	0	400		0	400		
T_A Operating free-air temperature		–55	125		–40	85		°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V_{CC}	$T_A = 25^\circ\text{C}$			SN54HC30		SN74HC30		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
V_{OH}	$V_I = V_{IH}$ or V_{IL} . $I_{OH} = -20 \mu\text{A}$	2 V	1.9	1.998		1.9		1.9		V
		4.5 V	4.4	4.499		4.4		4.4		
		6 V	5.9	5.999		5.9		5.9		
	$V_I = V_{IH}$ or V_{IL} . $I_{OH} = -4 \text{ mA}$	4.5 V	3.98	4.30		3.7		3.84		
V_{OL}	$V_I = V_{IH}$ or V_{IL} . $I_{OH} = -5.2 \text{ mA}$	6 V	5.48	5.80		5.2		5.34		V
	$V_I = V_{IH}$ or V_{IL} . $I_{OL} = 20 \mu\text{A}$	2 V	0.002	0.1		0.1		0.1		
		4.5 V	0.001	0.1		0.1		0.1		
		6 V	0.001	0.1		0.1		0.1		
	$V_I = V_{IH}$ or V_{IL} . $I_{OL} = 4 \text{ mA}$	4.5 V	0.17	0.26		0.4		0.33		
	$V_I = V_{IH}$ or V_{IL} . $I_{OL} = 5.2 \text{ mA}$	6 V	0.15	0.26		0.4		0.33		
I_I	$V_I = V_{CC}$ or 0	6 V	±0.1	±100		±1000		±1000		nA
I_{CC}	$V_I = V_{CC}$ or 0, $I_O = 0$	6 V		2		40		20		μA
C_i		2 to 6 V		3	10		10		10	pF

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switching characteristics over recommended operating free-air temperature range (unless otherwise noted), $C_L = 50 \text{ pF}$ (see Note 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CC}	$T_A = 25^\circ\text{C}$			SN54HC30		SN74HC30		UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t_{pd}	A thru H	Y	2 V		51	130		195		165	ns
			4.5 V		15	26		39		33	
			6 V		12	22		33		28	
t_t		Y	2 V		28	75		110		95	ns
			4.5 V		8	15		22		19	
			6 V		6	13		19		16	

C_{pd}	Power dissipation capacitance per gate	No load, $T_A = 25^\circ\text{C}$	22 pF typ
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NOTE 1: Load circuit and voltage waveforms are shown in Section 1.

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